

### 16.2.4 Translation Equations to Reference Conditions

The most basic translation equations for a solar cell are based on the diode model with series and shunt resistances discussed in Chapters 3 and 7. This model has been extended to modules by combining them in series and parallel combinations [55].

To a first order, short-circuit current ( $I_{SC}$ ), open-circuit voltage ( $V_{OC}$ ),  $P_{max}$ , and fill factor ( $FF$ ) are linear with temperature, whereas the current is linear with  $E_{tot}$  [49, 56–60]. These linear translation equations allow the performance under standard reference conditions to be translated to other conditions for energy-based rating methods. Typical temperature coefficients for various PV technologies are summarized in Table 16.5 and Figure 16.5.

A set of translation equations for current and voltage based on the work of Sandstrom has been implemented in consensus standards [61, 62]. These equations translate the entire current versus voltage ( $I-V$ ) curve for temperature and irradiance. Following the notation of the international standard in Reference [62], the following equations allow one to translate the current  $I_1$  and voltage  $V_1$  measured from temperature  $T_1$  to  $T_2$  and irradiance  $E_1$  to  $E_2$ :

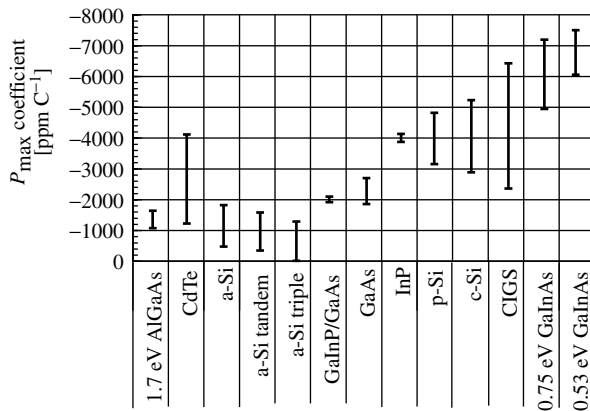
$$I_2 = I_1 + I_{SC1} \left( \frac{E_2}{E_1} - 1 \right) + \alpha(T_2 - T_1) \tag{16.4}$$

$$V_2 = V_1 - R_s(I_2 - I_1) - I_2K(T_2 - T_1) + \beta(T_2 - T_1), \tag{16.5}$$

where  $\alpha$  and  $\beta$  are the temperature coefficients,  $R_s$  is the series resistance, and  $K$  is a curve-shape correction factor. Applying equations (16.4) and (16.5) at a fixed irradiance

**Table 16.5** Typical Si solar cell temperature coefficients [57]

Type	$-V_{OC}$ [ppm/°C]	$I_{SC}$ [ppm/°C]	$-FF$ [ppm/°C]	$-P_{max}$ [ppm/°C]
Si cells & modules	2400–4500	400–980	940–1700	2600–5500



**Figure 16.5** Typical  $P_{max}$  temperature coefficients of various PV technologies [57]